Patent Claims

- 1. Use of materials based on quasi-one-dimensional transition metal ternary compounds M_xH_yHa_z (where M is a transition metal Mo, W, Ta, Nb; H is sulfur (S), selenium (Se), tellurium (Te); Ha is iodine (I)) and/or doped quasi-one-dimensional transition metal ternary compounds M_xH_yHa_z (where M=Ta, Ti, Nb; H is sulfur (S), selenium (Se), tellurium (Te); Ha is iodine (I)) doped with elements of group lb (silver (Ag), gold (Au), or copper (Cu)) as electron emitters under the influence of an external electric field.
- 2. Materials according to Claim 1, characterized in that the percentage of quasi-one-dimensional transition metal ternary compounds and/or doped quasi-one-dimensional transition metal ternary compounds doped with elements of group 1b in the active material ranges from 0.01 to 99.9 %, the rest consisting of additives in the form of conducting, non-conducting or semi-conducting compounds or composites.
- 3. Use of materials according to Claims 1 and 2, characterized in that electron emission takes place at a pressure below 1 mbar.
- 4. Electron emitters under the influence of an external electric field, characterized in that they are made of materials based on quasi-one-dimensional transition metal ternary compounds M_xH_yHa_z (where M is a transition metal Mo, W, Ta, Nb; H is sulfur (S), selenium (Se), tellurium

- (Te); Ha is iodine (I)) and/or doped quasi-one-dimensional transition metal ternary compounds $M_xH_yHa_z$ (where M=Ta, Ti, Nb; H is sulfur (S), selenium (Se), tellurium (Te); Ha is iodine (I)) doped with elements of group 1b (silver (Ag), gold (Au), or copper (Cu)).
- 5. Electron emitters according to Claim 4, characterized in that the percentage in such materials of quasi-one-dimensional transition metal ternary compounds and/or doped quasi-onedimensional transition metal ternary compounds doped with elements of group 1b in the active material ranges from 0.01 to 99.9 %, the rest consisting of additives in the form of conducting, non-conducting or semi-conducting compounds or composites.
- 6. Use of materials according to Claims 4 and 5, characterized in that electron emission takes place at a pressure below 1 mbar.